

SEMITRANS® 3

High Speed IGBT4 Modules

SKM150GAR12F4G

Features*

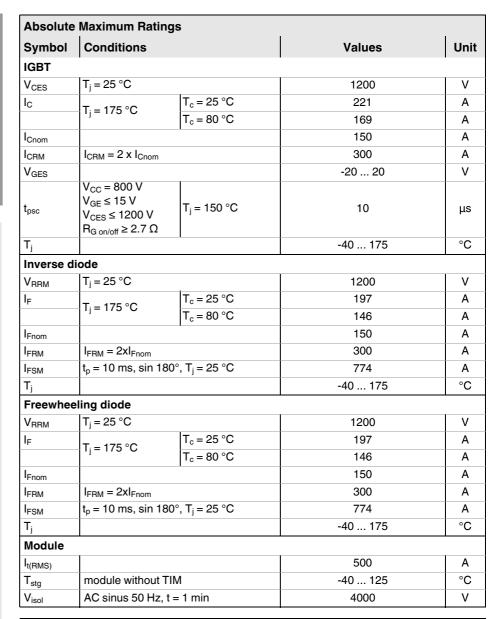
- · High speed trench and field-stop IGBT
- CAL4 ultra-fast = soft switching 4. generation CAL-diode
- Insulated copper baseplate using DBC technology (Direct Bonded Copper)
- · Increased power cycling capability
- For higher switching frequencies above 15kHz
- UL recognized, file no. E63532

Typical Applications

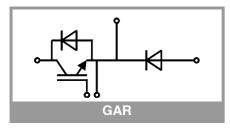
- · Electronic welders
- DC/DC converter
- · Brake chopper
- · Switched reluctance motor

Remarks

- · Case temperature limited to $T_c = 125^{\circ}C$ max.
- Recommended T_{op} = -40 ... +150°C
- Product reliability results valid for $T_i = 150$ °C



Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
IGBT			•			
· CE(Sat)	$I_C = 150 \text{ A}$ $V_{GE} = 15 \text{ V}$ chiplevel	T _j = 25 °C		2.05	2.42	٧
		T _j = 150 °C		2.60	2.93	٧
V _{CE0}	chiplevel	T _j = 25 °C		1.10	1.28	V
		T _j = 150 °C		0.95	1.13	V
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		6.3	7.6	mΩ
		T _j = 150 °C		11	12	mΩ
$V_{GE(th)}$	$V_{GE}=V_{CE}$, $I_C=5.2$ mA		5.2	5.8	6.4	V
I _{CES}	V _{GE} = 0 V V _{CE} = 1200 V	T _j = 25 °C			2.0	mA
		T _j = 150 °C		-		mA
C _{ies}	$V_{CE} = 25 \text{ V}$ $V_{GE} = 0 \text{ V}$	f = 1 MHz		8.8		nF
Coes		f = 1 MHz		0.58		nF
C _{res}		f = 1 MHz		0.47		nF
Q_{G}	V _{GE} = - 8 V+ 15 V			850		nC
R _{Gint}	$T_j = 25 ^{\circ}\text{C}$			2.4		Ω





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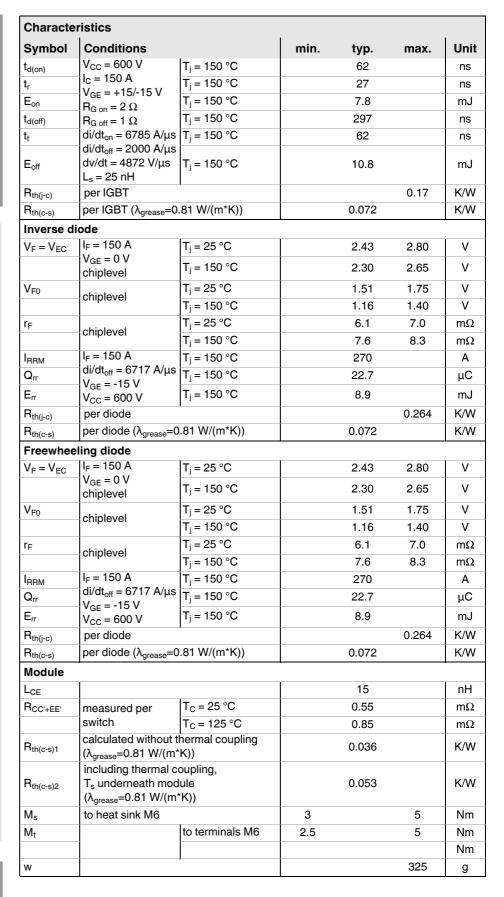
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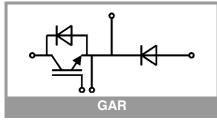
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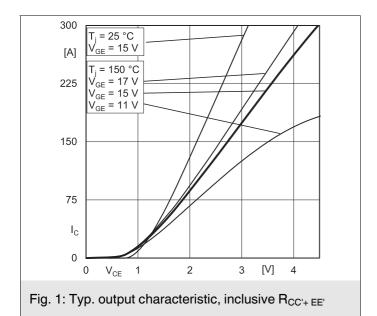
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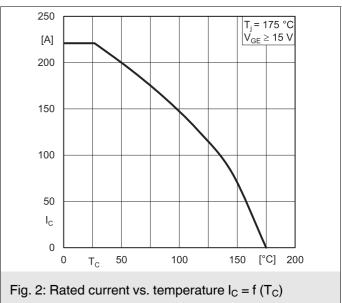
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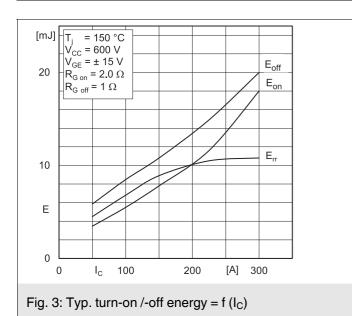
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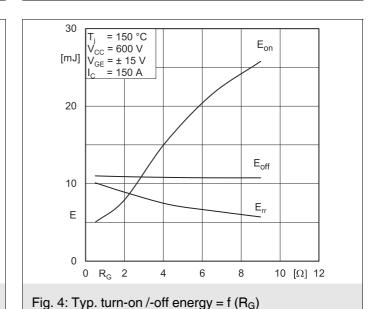


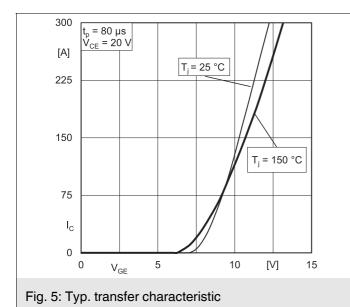


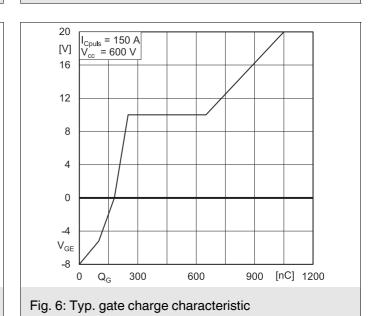


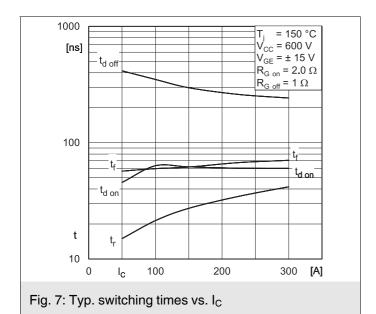


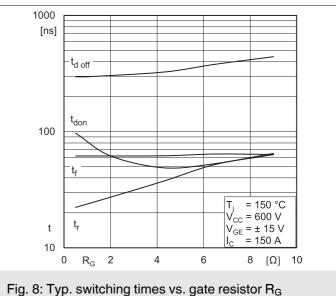


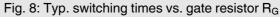


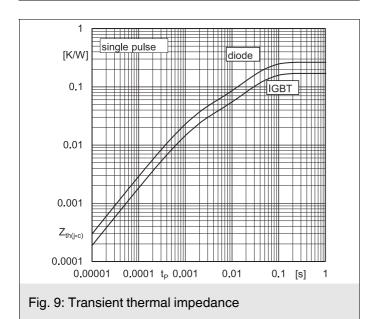












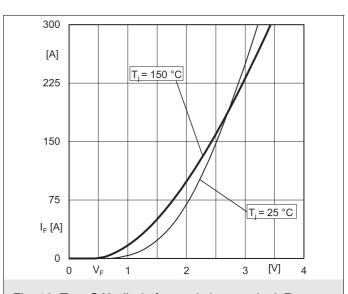
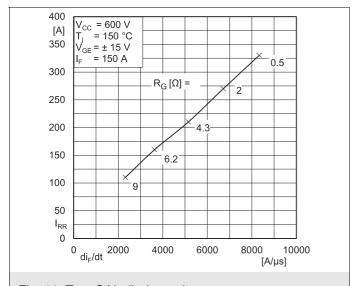


Fig. 10: Typ. CAL diode forward charact., incl. R_{CC'+ EE'}



 $V_{CC} = 600 \text{ V}$ 0.5 = 150 °C [µC] 300 V_{GE} = ± 15 V $R_G[\Omega] =$ 2 30 225 6.2 150 20 100 $=I_{F}[A]$ 10 Q_{rr} 0 0 di_F/dt 4000 8000 [A/µs]

Fig. 12: Typ. CAL diode peak reverse recovery charge

Fig. 11: Typ. CAL diode peak reverse recovery current

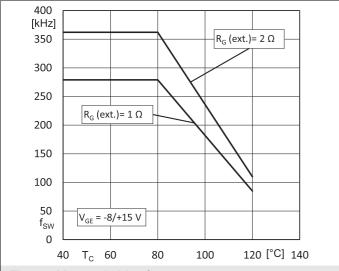
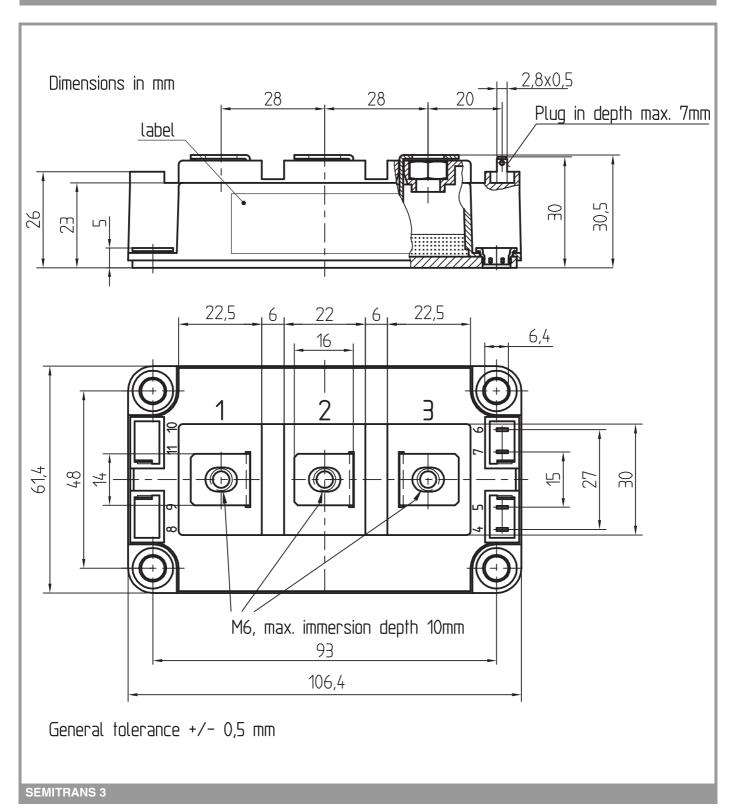
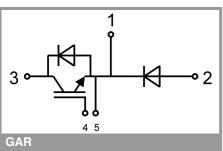


Fig. 13: Max. switching frequency vs. case temperature $f_{\text{sw}} = f(T_{\text{c}})$





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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